



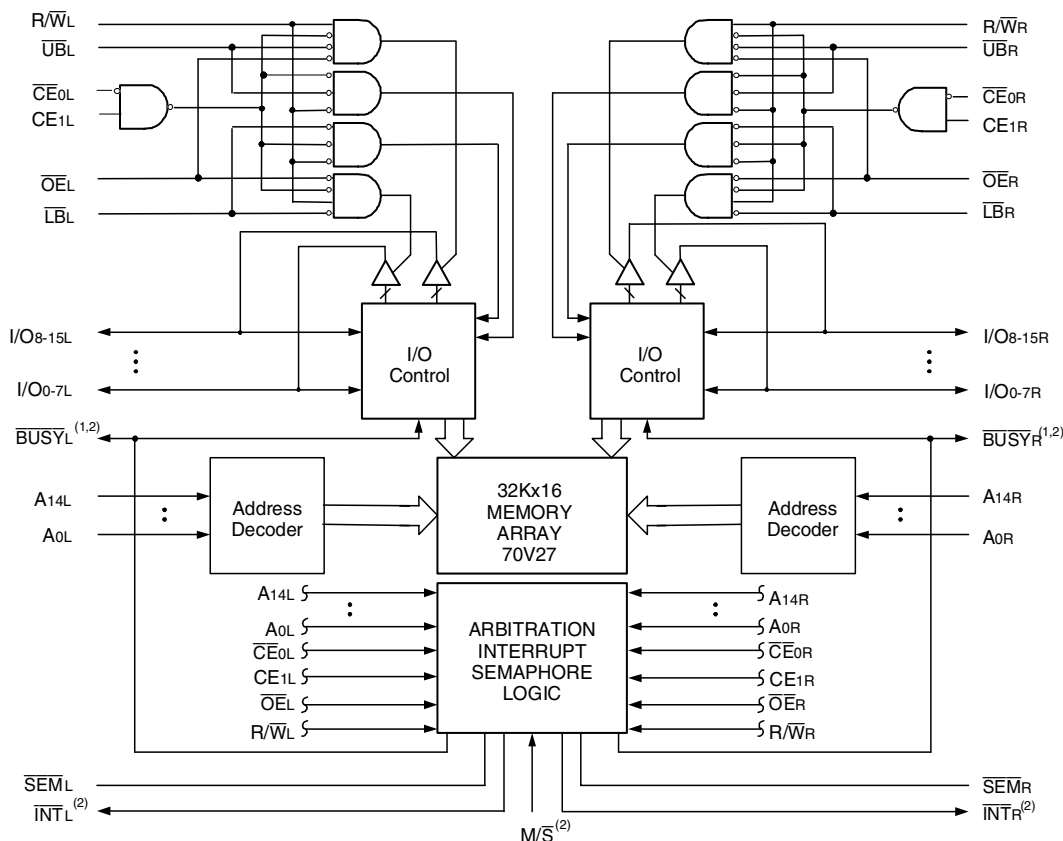
HIGH-SPEED 3.3V 32K x 16 DUAL-PORT STATIC RAM

IDT70V27S/L

Features:

- ♦ True Dual-Ported memory cells which allow simultaneous access of the same memory location
- ♦ High-speed access
 - Commercial: 15/20/25/35/55ns (max.)
 - Industrial: 20/35ns (max.)
- ♦ Low-power operation
 - IDT70V27S
 - Active: 500mW (typ.)
 - Standby: 3.3mW (typ.)
 - IDT70V27L
 - Active: 500mW (typ.)
 - Standby: 660μW (typ.)
- ♦ Separate upper-byte and lower-byte control for bus matching capability
- ♦ Dual chip enables allow for depth expansion without external logic
- ♦ IDT70V27 easily expands data bus width to 32 bits or more using the Master/Slave select when cascading more than one device
- ♦ $\overline{M/\overline{S}} = V_{IH}$ for \overline{BUSY} output flag on Master, $\overline{M/\overline{S}} = V_{IL}$ for \overline{BUSY} input on Slave
- ♦ Busy and Interrupt Flags
- ♦ On-chip port arbitration logic
- ♦ Full on-chip hardware support of semaphore signaling between ports
- ♦ Fully asynchronous operation from either port
- ♦ LVTTTL-compatible, single 3.3V ($\pm 0.3V$) power supply
- ♦ Available in 100-pin Thin Quad Flatpack (TQFP), and 144-pin Fine Pitch BGA (fpBGA)
- ♦ Industrial temperature range ($-40^{\circ}C$ to $+85^{\circ}C$) is available for selected speeds
- ♦ Green parts available, see ordering information

Functional Block Diagram



NOTES:

- 1) \overline{BUSY} is an input as a Slave ($\overline{M/\overline{S}} = V_{IL}$) and an output as a Master ($\overline{M/\overline{S}} = V_{IH}$).
- 2) \overline{BUSY} and \overline{INT} are non-tri-state totem-pole outputs (push-pull).

3603 drw 01

SEPTEMBER 2012

Description:

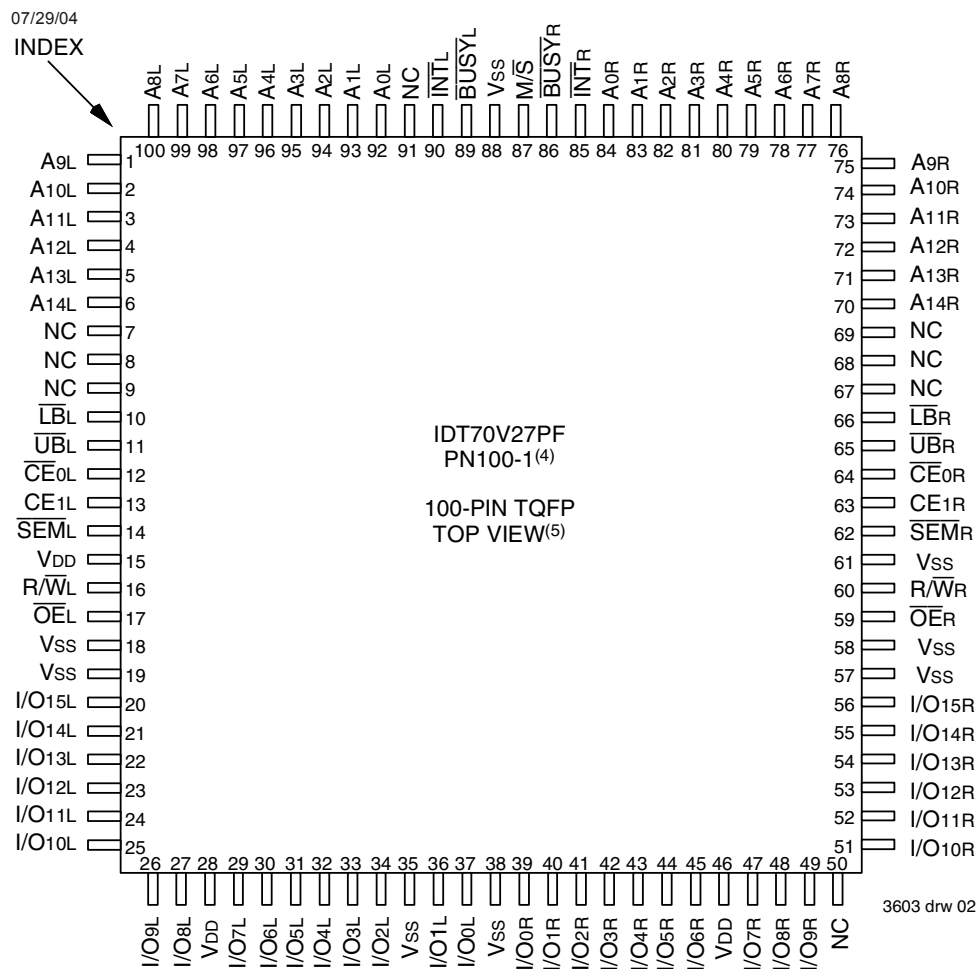
The IDT70V27 is a high-speed 32K x 16 Dual-Port Static RAM, designed to be used as a stand-alone 512K-bit Dual-Port RAM or as a combination MASTER/SLAVE Dual-Port RAM for 32-bit and wider word systems. Using the IDT MASTER/SLAVE Dual-Port RAM approach in 32-bit or wider memory system applications results in full-speed, error-free operation without the need for additional discrete logic.

The device provides two independent ports with separate control, address, and I/O pins that permit independent, asynchronous access for

reads or writes to any location in memory. An automatic power down feature controlled by the chip enables (\overline{CE}_0 and CE_1) permits the on-chip circuitry of each port to enter a very low standby power mode.

Fabricated using CMOS high-performance technology, these devices typically operate on only 500mW of power. The IDT70V27 is packaged in a 100-pin Thin Quad Flatpack (TQFP) and a 144-pin Fine Pitch BGA (fp BGA).

Pin Configurations^(1,2,3)



NOTES:

1. All VDD pins must be connected to power supply.
2. All VSS pins must be connected to ground supply.
3. Package body is approximately 14mm x 14mm x 1.4mm.
4. This package code is used to reference the package diagram.
5. This text does not indicate orientation of the actual part-marking.

Pin Configurations^(1,2,3) (con't.)

07/29/04

A1 NC	A2 NC	A3 A8L	A4 A5L	A5 A1L	A6 $\overline{\text{INTL}}$	A7 Vss	A8 $\overline{\text{BUSYR}}$	A9 A1R	A10 A5R	A11 NC	A12 NC	A13 NC
B1 NC	B2 NC	B3 NC	B4 A6L	B5 A2L	B6 NC	B7 $\text{M}/\overline{\text{S}}$	B8 $\overline{\text{INTR}}$	B9 A2R	B10 A6R	B11 NC	B12 NC	B13 NC
C1 A10L	C2 A9L	C3 NC	C4 A7L	C5 A3L	C6 NC	C7 NC	C8 NC	C9 A3R	C10 A7R	C11 A9R	C12 A10R	C13 A11R
D1 A14L	D2 A13L	D3 A12L	D4 A11L	D5 A4L	D6 A0L	D7 $\overline{\text{BUSYL}}$	D8 A0R	D9 A4R	D10 A8R	D11 A12R	D12 A13R	D13 A14R
E1 $\overline{\text{LBL}}$	E2 NC	E3 NC	E4 NC	IDT70V27BF BF144-1 ⁽⁴⁾ 144-Pin fpBGA Top View ⁽⁵⁾					E10 NC	E11 NC	E12 NC	E13 $\overline{\text{LBR}}$
F1 $\overline{\text{SEML}}$	F2 CE1L	F3 $\overline{\text{CE0L}}$	F4 $\overline{\text{UBL}}$						F10 $\overline{\text{UBR}}$	F11 $\overline{\text{CE0R}}$	F12 CE1R	F13 $\overline{\text{SEMR}}$
G1 VDD	G2 VDD	G3 VDD	G4 NC						G10 NC	G11 NC	G12 Vss	G13 Vss
H1 NC	H2 R/WL	H3 $\overline{\text{OEL}}$	H4 NC						H10 NC	H11 $\overline{\text{OER}}$	H12 R/WR	H13 Vss
J1 Vss	J2 I/O15L	J3 I/O14L	J4 I/O13L						J10 I/O13R	J11 I/O14R	J12 I/O15R	J13 Vss
K1 I/O12L	K2 NC	K3 NC	K4 NC	K5 I/O6L	K6 I/O3L	K7 I/O0R	K8 I/O3R	K9 I/O6R	K10 I/O11R	K11 NC	K12 NC	K13 I/O12R
L1 I/O11L	L2 I/O10L	L3 NC	L4 NC	L5 I/O5L	L6 I/O2L	L7 Vss	L8 VDD	L9 I/O5R	L10 NC	L11 NC	L12 NC	L13 I/O10R
M1 I/O9L	M2 NC	M3 NC	M4 VDD	M5 I/O4L	M6 Vss	M7 I/O0L	M8 I/O2R	M9 I/O4R	M10 I/O7R	M11 I/O8R	M12 NC	M13 I/O9R
N1 NC	N2 NC	N3 I/O8L	N4 I/O7L	N5 NC	N6 I/O1L	N7 VDD	N8 I/O1R	N9 NC	N10 VDD	N11 NC	N12 NC	N13 NC

3603 drw 02a

NOTES:

1. All VDD pins must be connected to power supply.
2. All Vss pins must be connected to ground supply.
3. Package body is approximately 12mm x 12mm x 1.4mm.
4. This package code is used to reference the package diagram.
5. This text does not indicate orientation of the actual part-marking.

Pin Names

Left Port	Right Port	Names
$\overline{\text{CE0L}}$, CE1L	$\overline{\text{CE0R}}$, CE1R	Chip Enable
R/WL	R/WR	Read/Write Enable
$\overline{\text{OEL}}$	$\overline{\text{OER}}$	Output Enable
A0L - A14L	A0R - A14R	Address
I/O0L - I/O15L	I/O0R - I/O15R	Data Input/Output
$\overline{\text{SEML}}$	$\overline{\text{SEMR}}$	Semaphore Enable
$\overline{\text{UBL}}$	$\overline{\text{UBR}}$	Upper Byte Select
$\overline{\text{LBL}}$	$\overline{\text{LBR}}$	Lower Byte Select
$\overline{\text{INTL}}$	$\overline{\text{INTR}}$	Interrupt Flag
$\overline{\text{BUSYL}}$	$\overline{\text{BUSYR}}$	Busy Flag
$\text{M}/\overline{\text{S}}$		Master or Slave Select
VDD		Power (3.3V)
Vss		Ground (0V)

3603 tbl 01

Truth Table I – Chip Enable^(1,2,3)

\overline{CE}	\overline{CE}_0	CE_1	Mode
L	V_{IL}	V_{IH}	Port Selected (TTL Active)
	$\leq 0.2V$	$\geq V_{DD} - 0.2V$	Port Selected (CMOS Active)
H	V_{IH}	X	Port Deselected (TTL Inactive)
	X	V_{IL}	Port Deselected (TTL Inactive)
	$\geq V_{DD} - 0.2V$	X	Port Deselected (CMOS Inactive)
	X	$\leq 0.2V$	Port Deselected (CMOS Inactive)

NOTES:

3603 tbl 02

1. Chip Enable references are shown above with the actual \overline{CE}_0 and CE_1 levels, \overline{CE} is a reference only.
2. Port "A" and "B" references are located where \overline{CE} is used.
3. "H" = V_{IH} and "L" = V_{IL}

Truth Table II – Non-Contention Read/Write Control

Inputs ⁽¹⁾						Outputs		Mode
$\overline{CE}^{(2)}$	R/\overline{W}	\overline{OE}	\overline{UB}	\overline{LB}	\overline{SEM}	I/O ₈₋₁₅	I/O ₀₋₇	
H	X	X	X	X	H	High-Z	High-Z	Deselected: Power-Down
X	X	X	H	H	H	High-Z	High-Z	Both Bytes Deselected
L	L	X	L	H	H	DATA _{IN}	High-Z	Write to Upper Byte Only
L	L	X	H	L	H	High-Z	DATA _{IN}	Write to Lower Byte Only
L	L	X	L	L	H	DATA _{IN}	DATA _{IN}	Write to Both Bytes
L	H	L	L	H	H	DATA _{OUT}	High-Z	Read Upper Byte Only
L	H	L	H	L	H	High-Z	DATA _{OUT}	Read Lower Byte Only
L	H	L	L	L	H	DATA _{OUT}	DATA _{OUT}	Read Both Bytes
X	X	H	X	X	X	High-Z	High-Z	Outputs Disabled

NOTES:

3603 tbl 03

1. A_{0L} — A_{14L} ≠ A_{0R} — A_{14R}.
2. Refer to Chip Enable Truth Table.

Truth Table III – Semaphore Read/Write Control

Inputs ⁽¹⁾						Outputs		Mode
$\overline{CE}^{(2)}$	R/\overline{W}	\overline{OE}	\overline{UB}	\overline{LB}	\overline{SEM}	I/O ₈₋₁₅	I/O ₀₋₇	
H	H	L	X	X	L	DATA _{OUT}	DATA _{OUT}	Read Data in Semaphore Flag
X	H	L	H	H	L	DATA _{OUT}	DATA _{OUT}	Read Data in Semaphore Flag
H	↑	X	X	X	L	DATA _{IN}	DATA _{IN}	Write I/O ₀ into Semaphore Flag
X	↑	X	H	H	L	DATA _{IN}	DATA _{IN}	Write I/O ₀ into Semaphore Flag
L	X	X	L	X	L	—	—	Not Allowed
L	X	X	X	L	L	—	—	Not Allowed

NOTES:

3603 tbl 04

1. There are eight semaphore flags written to I/O₀ and read from all the I/Os (I/O₀-I/O₁₅). These eight semaphore flags are addressed by A₀-A₂.
2. Refer to Chip Enable Truth Table.

Absolute Maximum Ratings⁽¹⁾

Symbol	Rating	Commercial & Industrial	Unit
V _{TERM} ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
T _{BIAS}	Temperature Under Bias	-55 to +125	°C
T _{STG}	Storage Temperature	-65 to +150	°C
I _{OUT}	DC Output Current	50	mA

3603 tbl 05

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{TERM} must not exceed V_{DD} + 0.3V for more than 25% of the cycle time or 10ns maximum, and is limited to ≤ 20mA for the period of V_{TERM} ≥ V_{DD} + 0.3V.

Capacitance⁽¹⁾

(T_A = +25°C, f = 1.0MHz) TQFP ONLY

Symbol	Parameter	Conditions	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	9	pF
C _{OUT} ⁽²⁾	Output Capacitance	V _{OUT} = 0V	10	pF

NOTES:

- This parameter is determined by device characterization but is not production tested.
- C_{OUT} also reference C_{I/O}.

Maximum Operating Temperature and Supply Voltage⁽¹⁾

Grade	Ambient Temperature	GND	V _{DD}
Commercial	0°C to +70°C	0V	3.3V ± 0.3V
Industrial	-40°C to +85°C	0V	3.3V ± 0.3V

3603 tbl 06

NOTES:

- This is the parameter T_A. This is the "instant on" case temperature.

Recommended DC Operating Conditions⁽¹⁾

Symbol	Parameter	Min.	Typ.	Max.	Unit
V _{DD}	Supply Voltage	3.0	3.3	3.6	V
V _{SS}	Ground	0	0	0	V
V _{IH}	Input High Voltage	2.0	—	V _{DD} +0.3V ⁽²⁾	V
V _{IL}	Input Low Voltage	-0.3 ⁽¹⁾	—	0.8	V

3603 tbl 07

NOTES:

- V_{IL} ≥ -1.5V for pulse width less than 10ns.
- V_{TERM} must not exceed V_{DD} + 0.3V.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range (V_{DD} = 3.3V ± 0.3V)

Symbol	Parameter	Test Conditions	70V27S		70V27L		Unit
			Min.	Max.	Min.	Max.	
I _{LI}	Input Leakage Current ⁽¹⁾	V _{DD} = 3.6V, V _{IN} = 0V to V _{DD}	—	10	—	5	μA
I _{LO}	Output Leakage Current	\overline{CE} = V _{IH} , V _{OUT} = 0V to V _{DD}	—	10	—	5	μA
V _{OL}	Output Low Voltage	I _{OL} = 4mA	—	0.4	—	0.4	V
V _{OH}	Output High Voltage	I _{OH} = -4mA	2.4	—	2.4	—	V

NOTE:

3603 tbl 09

- At V_{DD} ≤ 2.0V, input leakages are undefined.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range^(1,6) ($V_{DD} = 3.3V \pm 0.3V$)

Symbol	Parameter	Test Condition	Version	70V27X15 Com'l Only		70V27X20 Com'l & Ind		70V27X25 Com'l Only		Unit
				Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	
IDD	Dynamic Operating Current (Both Ports Active)	$\overline{CE} = V_{IL}$, Outputs Disabled $\overline{SEM} = V_{IH}$ $f = f_{MAX}^{(3)}$	COM'L S	170	260	165	255	145	245	mA
			L	170	225	165	220	145	210	
			IND'L S	—	—	—	—	—	—	
			L	—	—	165	230	—	—	
ISB1	Standby Current (Both Ports - TTL Level Inputs)	$\overline{CE}_L = \overline{CE}_R = V_{IH}$ $\overline{SEM}_R = \overline{SEM}_L = V_{IH}$ $f = f_{MAX}^{(3)}$	COM'L S	44	70	39	60	27	50	mA
			L	44	60	39	50	27	40	
			IND'L S	—	—	—	—	—	—	
			L	—	—	39	55	—	—	
ISB2	Standby Current (One Port - TTL Level Inputs)	$\overline{CE}^{*A} = V_{IL}$ and $\overline{CE}^{*B} = V_{IH}^{(5)}$ Active Port Outputs Disabled, $f = f_{MAX}^{(3)}$ $\overline{SEM}_R = \overline{SEM}_L = V_{IH}$	COM'L S	115	160	105	155	90	150	mA
			L	115	145	105	140	90	135	
			IND'L S	—	—	—	—	—	—	
			L	—	—	105	150	—	—	
ISB3	Full Standby Current (Both Ports - All CMOS Level Inputs)	Both Ports \overline{CE}_L and $\overline{CE}_R \geq V_{DD} - 0.2V$ $V_{IN} \geq V_{DD} - 0.2V$ or $V_{IN} \leq 0.2V$, $f = 0^{(4)}$ $\overline{SEM}_R = \overline{SEM}_L \geq V_{DD} - 0.2V$	COM'L S	1.0	6	1.0	6	1.0	6	mA
			L	0.2	3	0.2	3	0.2	3	
			IND'L S	—	—	—	—	—	—	
			L	—	—	0.2	6	—	—	
ISB4	Full Standby Current (One Port - All CMOS Level Inputs)	$\overline{CE}^{*A} \leq 0.2V$ and $\overline{CE}^{*B} \geq V_{DD} - 0.2V^{(5)}$ $\overline{SEM}_R = \overline{SEM}_L \geq V_{DD} - 0.2V$ $V_{IN} \geq V_{DD} - 0.2V$ or $V_{IN} \leq 0.2V$ Active Port Outputs Disabled $f = f_{MAX}^{(3)}$	COM'L S	115	155	105	150	90	145	mA
			L	115	140	105	135	90	130	
			IND'L S	—	—	—	—	—	—	
			L	—	—	105	145	—	—	

3603 tbl 10a

NOTES:

- 'X' in part numbers indicates power rating (S or L).
- $V_{DD} = 3.3V$, $T_A = +25^\circ C$, and are not production tested. $I_{DD} DC = 90mA$ (Typ.)
- At $f = f_{MAX}$, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of 1/trc, and using "AC Test Conditions" of input levels of GND to 3V.
- $f = 0$ means no address or control lines change.
- Port "A" may be either left or right port. Port "B" is the opposite from port "A".
- Refer to Chip Enable Truth Table.

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range^(1,6) ($V_{DD} = 3.3V \pm 0.3V$)

Symbol	Parameter	Test Condition	Version	70V27X35 Com'l & Ind		70V27X55 Com'l Only		Unit
				Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	
IDD	Dynamic Operating Current (Both Ports Active)	$\overline{CE} = V_{IL}$, Outputs Disabled $\overline{SEM} = V_{IH}$ $f = f_{MAX}^{(3)}$	COM'L S	135	235	125	225	mA
			IND'L S	135	190	125	180	
ISB1	Standby Current (Both Ports - TTL Level Inputs)	$\overline{CE}_L = \overline{CE}_R = V_{IH}$ $\overline{SEM}_R = \overline{SEM}_L = V_{IH}$ $f = f_{MAX}^{(3)}$	COM'L S	22	45	15	40	mA
			IND'L S	22	35	15	30	
ISB2	Standby Current (One Port - TTL Level Inputs)	$\overline{CE}^*A = V_{IL}$ and $\overline{CE}^*B = V_{IH}^{(5)}$ Active Port Outputs Disabled, $f = f_{MAX}^{(3)}$ $\overline{SEM}_R = \overline{SEM}_L = V_{IH}$	COM'L S	85	140	75	140	mA
			IND'L S	85	125	75	125	
ISB3	Full Standby Current (Both Ports - All CMOS Level Inputs)	Both Ports \overline{CE}_L and $\overline{CE}_R \geq V_{DD} - 0.2V$ $V_{IN} \geq V_{DD} - 0.2V$ or $V_{IN} \leq 0.2V$, $f = 0^{(4)}$ $\overline{SEM}_R = \overline{SEM}_L \geq V_{DD} - 0.2V$	COM'L S	1.0	6	1.0	6	mA
			IND'L S	0.2	3	0.2	3	
ISB4	Full Standby Current (One Port - All CMOS Level Inputs)	$\overline{CE}^*A \leq 0.2V$ and $\overline{CE}^*B \geq V_{DD} - 0.2V^{(5)}$ $\overline{SEM}_R = \overline{SEM}_L \geq V_{DD} - 0.2V$ $V_{IN} \geq V_{DD} - 0.2V$ or $V_{IN} \leq 0.2V$ Active Port Outputs Disabled $f = f_{MAX}^{(3)}$	COM'L S	85	135	75	135	mA
			IND'L S	85	120	75	120	

3603 tbl 10b

NOTES:

- 'X' in part numbers indicates power rating (S or L).
- $V_{DD} = 3.3V$, $T_A = +25^\circ C$, and are not production tested. $I_{DD} DC = 90mA$ (Typ.)
- At $f = f_{MAX}$, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of $1/t_{RC}$, and using "AC Test Conditions" of input levels of GND to 3V.
- $f = 0$ means no address or control lines change.
- Port "A" may be either left or right port. Port "B" is the opposite from port "A".
- Refer to Chip Enable Truth Table.

AC Test Conditions

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	3ns Max.
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	Figures 1 and 2

3603 tbl 11

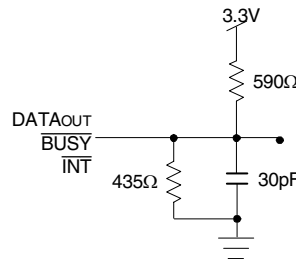


Figure 1. AC Output Test Load

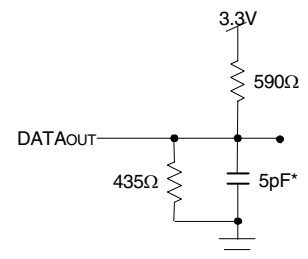


Figure 2. Output Test Load
(for tLZ, tHZ, tWZ, tOW)
*Including scope and jig

3603 drw 04

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range⁽⁴⁾

Symbol	Parameter	70V27X15 Com'l Only		70V27X20 Com'l & Ind		70V27X25 Com'l Only		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE								
t _{RC}	Read Cycle Time	15	—	20	—	25	—	ns
t _{AA}	Address Access Time	—	15	—	20	—	25	ns
t _{ACE}	Chip Enable Access Time ⁽³⁾	—	15	—	20	—	25	ns
t _{ABE}	Byte Enable Access Time ⁽³⁾	—	15	—	20	—	25	ns
t _{AOE}	Output Enable Access Time	—	10	—	12	—	15	ns
t _{OH}	Output Hold from Address Change	3	—	3	—	3	—	ns
t _{LZ}	Output Low-Z Time ^(1,2)	3	—	3	—	3	—	ns
t _{HZ}	Output High-Z Time ^(1,2)	—	12	—	12	—	15	ns
t _{PU}	Chip Enable to Power Up Time ^(2,5)	0	—	0	—	0	—	ns
t _{PD}	Chip Disable to Power Down Time ^(2,5)	—	15	—	20	—	25	ns
t _{SOP}	Semaphore Flag Update Pulse (\overline{OE} or \overline{SEM})	10	—	10	—	15	—	ns
t _{SAA}	Semaphore Address Access Time	—	15	—	20	—	35	ns

3603 tbl 12a

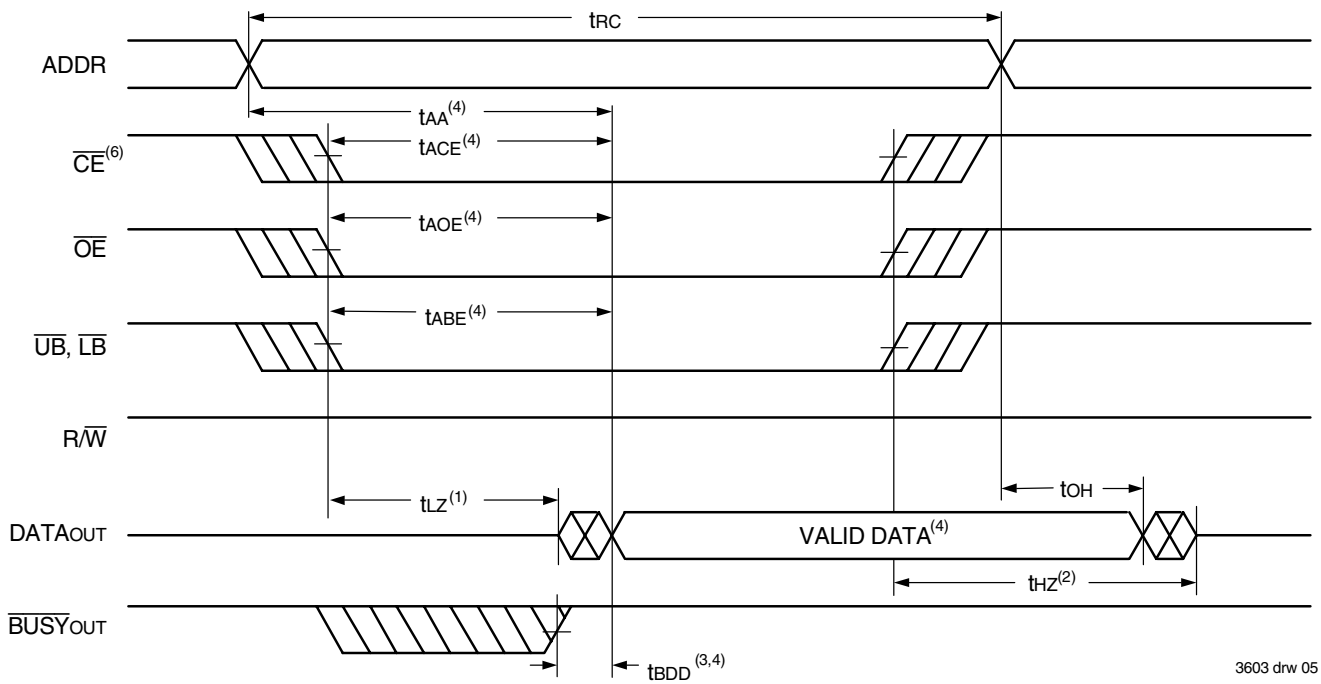
Symbol	Parameter	70V27X35 Com'l & Ind		70V27X55 Com'l Only		Unit
		Min.	Max.	Min.	Max.	
READ CYCLE						
tRC	Read Cycle Time	35	—	55	—	ns
tAA	Address Access Time	—	35	—	55	ns
tACE	Chip Enable Access Time ⁽³⁾	—	35	—	55	ns
tABE	Byte Enable Access Time ⁽³⁾	—	35	—	55	ns
tAOE	Output Enable Access Time	—	20	—	30	ns
tOH	Output Hold from Address Change	3	—	3	—	ns
tLZ	Output Low-Z Time ^(1,2)	3	—	3	—	ns
tHZ	Output High-Z Time ^(1,2)	—	20	—	25	ns
tPU	Chip Enable to Power Up Time ^(2,5)	0	—	0	—	ns
tPD	Chip Disable to Power Down Time ^(2,5)	—	45	—	50	ns
tSOP	Semaphore Flag Update Pulse (\overline{OE} or \overline{SEM})	15	—	15	—	ns
tSAA	Semaphore Address Access Time	—	45	—	65	ns

3603 tbl 12b

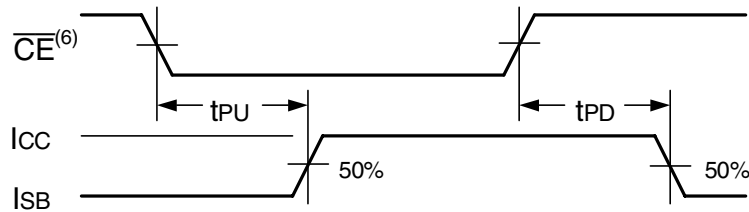
NOTES:

1. Transition is measured 0mV from Low or High-impedance voltage with Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization, but is not production tested.
3. To access RAM, $\overline{CE} = V_{IL}$ and $\overline{SEM} = V_{IH}$. To access semaphore, $\overline{CE} = V_{IH}$ and $\overline{SEM} = V_{IL}$.
4. 'X' in part numbers indicates power rating (S or L).
5. Refer to Chip Enable Truth Table.

Waveform of Read Cycles⁽⁵⁾



Timing of Power-Up Power-Down



NOTES:

1. Timing depends on which signal is asserted last: \overline{CE} , \overline{OE} , \overline{LB} , or \overline{UB} .
2. Timing depends on which signal is de-asserted first: \overline{CE} , \overline{OE} , \overline{LB} , or \overline{UB} .
3. t_{BDD} delay is required only in cases where the opposite port is completing a write operation to the same address location. For simultaneous read operations \overline{BUSY} has no relation to valid output data.
4. Start of valid data depends on which timing becomes effective last: t_{AOE} , t_{ACE} , t_{AA} or t_{BDD} .
5. $\overline{SEM} = V_{IH}$.
6. Refer to Chip Enable Truth Table.

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage⁽⁵⁾

Symbol	Parameter	70V27X15 Com'l Only		70V27X20 Com'l & Ind		70V27X25 Com'l Only		Unit	
		Min.	Max.	Min.	Max.	Min.	Max.		
WRITE CYCLE									
tWC	Write Cycle Time	15	—	20	—	25	—	ns	
tEW	Chip Enable to End-of-Write ⁽³⁾	12	—	15	—	20	—	ns	
tAW	Address Valid to End-of-Write	12	—	15	—	20	—	ns	
tAS	Address Set-up Time ⁽³⁾	0	—	0	—	0	—	ns	
tWP	Write Pulse Width	12	—	15	—	20	—	ns	
tWR	Write Recovery Time	0	—	0	—	0	—	ns	
tDW	Data Valid to End-of-Write	10	—	15	—	15	—	ns	
tHZ	Output High-Z Time ^(1,2)	—	10	—	10	—	15	ns	
tDH	Data Hold Time ⁽⁴⁾	0	—	0	—	0	—	ns	
tWZ	Write Enable to Output in High-Z ^(1,2)	—	10	—	10	—	15	ns	
tOW	Output Active from End-of-Write ^(1,2,4)	0	—	0	—	0	—	ns	
tSWRD	$\overline{\text{SEM}}$ Flag Write to Read Time	5	—	5	—	5	—	ns	
tSPS	$\overline{\text{SEM}}$ Flag Contention Window	5	—	5	—	5	—	ns	

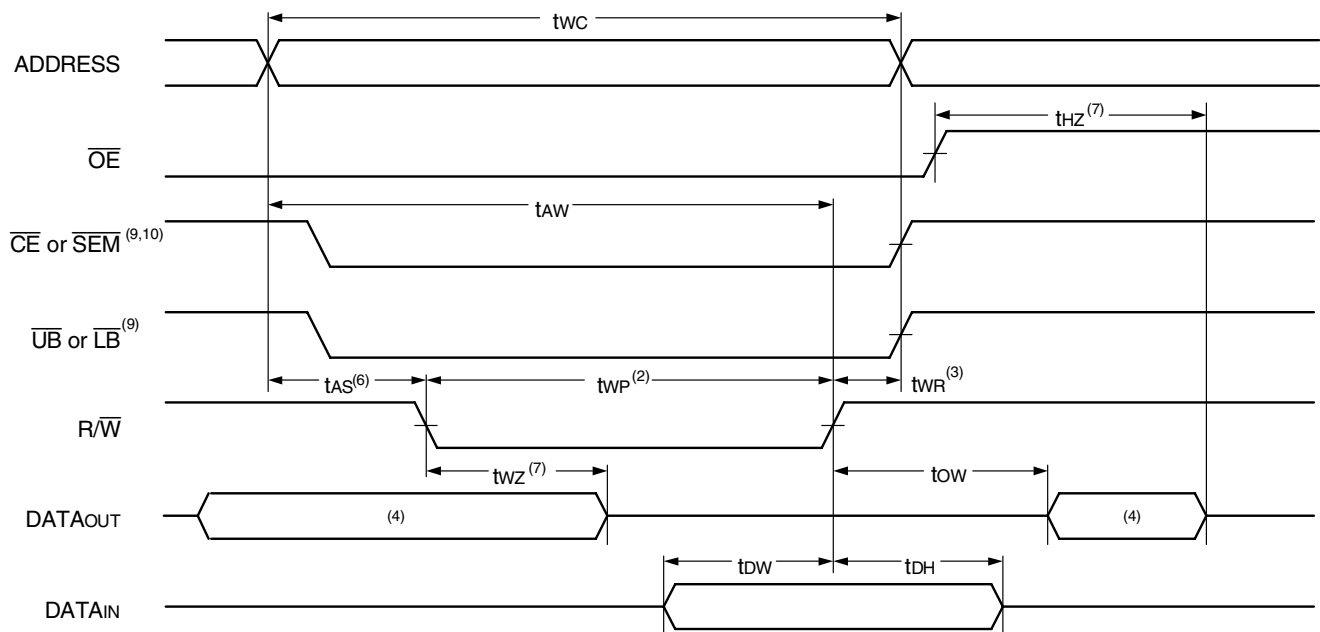
3603 tbl 13a

Symbol	Parameter	70V27X35 Com'l & Ind		70V27X55 Com'l Only		Unit
		Min.	Max.	Min.	Max.	
WRITE CYCLE						
tWC	Write Cycle Time	35	—	55	—	ns
tEW	Chip Enable to End-of-Write ⁽³⁾	30	—	45	—	ns
tAW	Address Valid to End-of-Write	30	—	45	—	ns
tAS	Address Set-up Time ⁽³⁾	0	—	0	—	ns
tWP	Write Pulse Width	25	—	40	—	ns
tWR	Write Recovery Time	0	—	0	—	ns
tDW	Data Valid to End-of-Write	20	—	30	—	ns
tHZ	Output High-Z Time ^(1,2)	—	20	—	25	ns
tDH	Data Hold Time ⁽⁴⁾	0	—	0	—	ns
twZ	Write Enable to Output in High-Z ^(1,2)	—	20	—	25	ns
tOW	Output Active from End-of-Write ^(1,2,4)	0	—	0	—	ns
tSWRD	$\overline{\text{SEM}}$ Flag Write to Read Time	5	—	5	—	ns
tSPS	$\overline{\text{SEM}}$ Flag Contention Window	5	—	5	—	ns

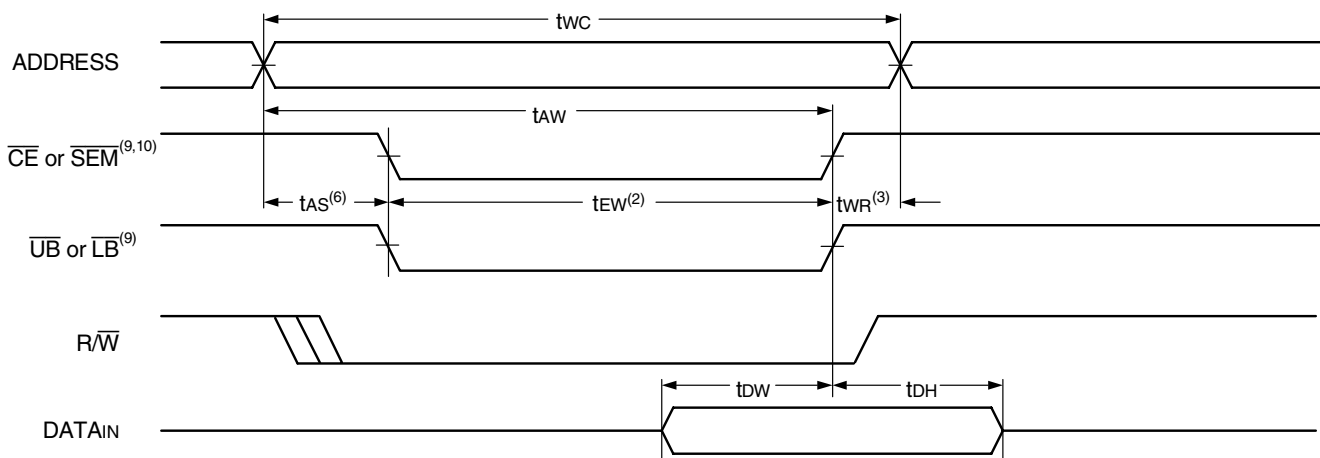
3603 tbl 13b

NOTES:

1. Transition is measured 0mV from Low or High-impedance voltage with Output Test Load (Figure 2).
2. This parameter is guaranteed by device characterization, but is not production tested.
3. To access RAM $\overline{\text{CE}} = \text{V}_{\text{IL}}$ and $\overline{\text{SEM}} = \text{V}_{\text{IH}}$. To access semaphore, $\overline{\text{CE}} = \text{V}_{\text{IH}}$ and $\overline{\text{SEM}} = \text{V}_{\text{IL}}$. Either condition must be valid for the entire t_{EW} time. Refer to Chip Enable Truth Table.
4. The specification for t_{DH} must be met by the device supplying write data to the RAM under all operating conditions. Although t_{DH} and t_{OW} values will vary over voltage and temperature, the actual t_{DH} will always be smaller than the actual t_{OW}.
5. 'X' in part numbers indicates power rating (S or L).

Timing Waveform of Write Cycle No. 1, $\overline{R/\overline{W}}$ Controlled Timing^(1,5,8)

3603 drw 07

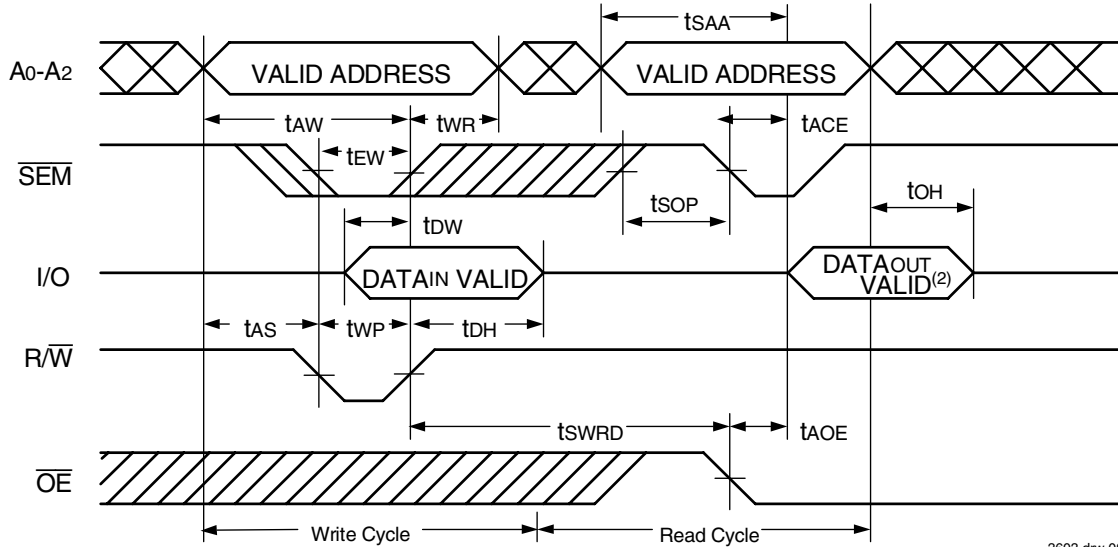
Timing Waveform of Write Cycle No. 2, \overline{CE} , \overline{UB} , \overline{LB} Controlled Timing^(1,5)

3603 drw 08

NOTES:

1. $\overline{R/\overline{W}}$ or \overline{CE} or \overline{UB} and \overline{LB} must be HIGH during all address transitions.
2. A write occurs during the overlap (t_{EW} or t_{WP}) of a LOW \overline{CE} and a LOW $\overline{R/\overline{W}}$ for memory array writing cycle.
3. t_{WR} is measured from the earlier of \overline{CE} or $\overline{R/\overline{W}}$ (or \overline{SEM} or $\overline{R/\overline{W}}$) going HIGH to the end of write cycle.
4. During this period, the I/O pins are in the output state and input signals must not be applied.
5. If the \overline{CE} or \overline{SEM} LOW transition occurs simultaneously with or after the $\overline{R/\overline{W}}$ LOW transition, the outputs remain in the High-impedance state.
6. Timing depends on which enable signal is asserted last, \overline{CE} or $\overline{R/\overline{W}}$.
7. This parameter is guaranteed by device characterization, but is not production tested. Transition is measured 0mV from steady state with the Output Test Load (Figure 2).
8. If \overline{OE} is LOW during $\overline{R/\overline{W}}$ controlled write cycle, the write pulse width must be the larger of t_{WP} or ($t_{WZ} + t_{DW}$) to allow the I/O drivers to turn off and data to be placed on the bus for the required t_{DW} . If \overline{OE} is HIGH during an $\overline{R/\overline{W}}$ controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified t_{WP} .
9. To access RAM, $\overline{CE} = V_{IL}$ and $\overline{SEM} = V_{IH}$. To access semaphore, $\overline{CE} = V_{IH}$ and $\overline{SEM} = V_{IL}$. t_{EW} must be met for either condition.
10. Refer to Chip Enable Truth Table.

Timing Waveform of Semaphore Read after Write Timing, Either Side⁽¹⁾

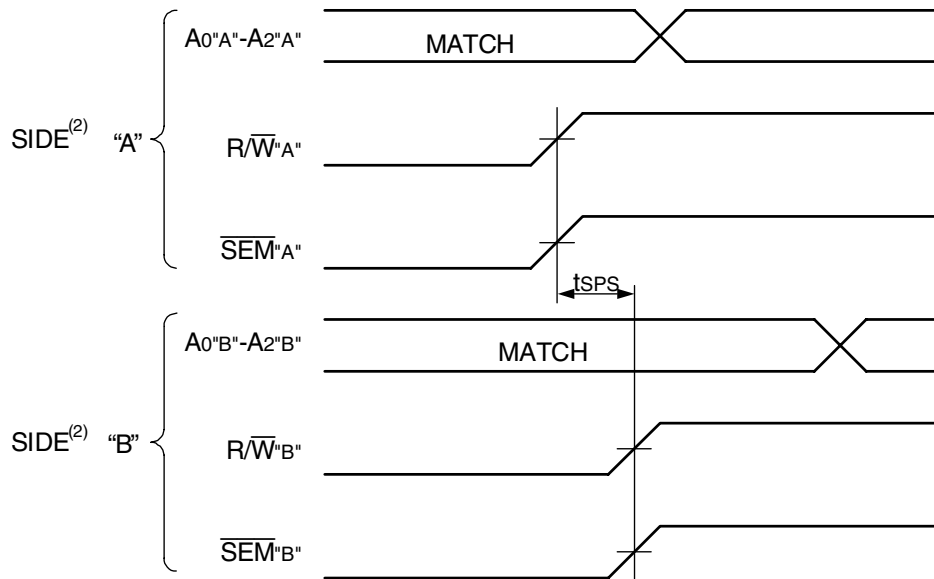


3603 drw 09

NOTES:

1. $\overline{CE} = V_{IH}$ or \overline{UB} and $\overline{LB} = V_{IH}$ for the duration of the above timing (both write and read cycle), refer to Chip Enable Truth Table.
2. "DATAOUT VALID" represents all I/O's (I/O₀-I/O₁₅) equal to the semaphore value.

Timing Waveform of Semaphore Write Contention^(1,3,4)



3603 drw 10

NOTES:

1. $DOR = DOL = V_{IL}$, $\overline{CE_R} = \overline{CE_L} = V_{IH}$, or both \overline{UB} & $\overline{LB} = V_{IH}$ (refer to Chip Enable Truth Table).
2. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is the opposite from port "A".
3. This parameter is measured from $R/W-A$ or $SEM-A$ going HIGH to $R/W-B$ or $SEM-B$ going HIGH.
4. If t_{SPS} is not satisfied, there is no guarantee which side will be granted the semaphore flag.

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range⁽⁶⁾

Symbol	Parameter	70V27X15 Com'l Only		70V27X20 Com'l & Ind		70V27X25 Com'l Only		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
BUSY TIMING (M/ \overline{S} =V _{IH})								
t _{BAA}	\overline{BUSY} Access Time from Address Match	—	15	—	20	—	25	ns
t _{BDA}	\overline{BUSY} Disable Time from Address Not Matched	—	15	—	20	—	25	ns
t _{BAC}	\overline{BUSY} Access Time from Chip Enable Low	—	15	—	20	—	25	ns
t _{BDC}	\overline{BUSY} Disable Time from Chip Enable High	—	15	—	20	—	25	ns
t _{APS}	Arbitration Priority Set-up Time ⁽²⁾	5	—	5	—	5	—	ns
t _{BDD}	\overline{BUSY} Disable to Valid Data ⁽³⁾	—	17	—	35	—	35	ns
t _{WH}	Write Hold After \overline{BUSY} ⁽⁵⁾	12	—	15	—	20	—	ns
BUSY TIMING (M/ \overline{S} =V _{IL})								
t _{WB}	\overline{BUSY} Input to Write ⁽⁴⁾	0	—	0	—	0	—	ns
t _{WH}	Write Hold After \overline{BUSY} ⁽⁵⁾	12	—	15	—	20	—	ns
PORT-TO-PORT DELAY TIMING								
t _{WDD}	Write Pulse to Data Delay ⁽¹⁾	—	30	—	45	—	55	ns
t _{DDD}	Write Data Valid to Read Data Delay ⁽¹⁾	—	25	—	30	—	50	ns

3603 tbl 14a

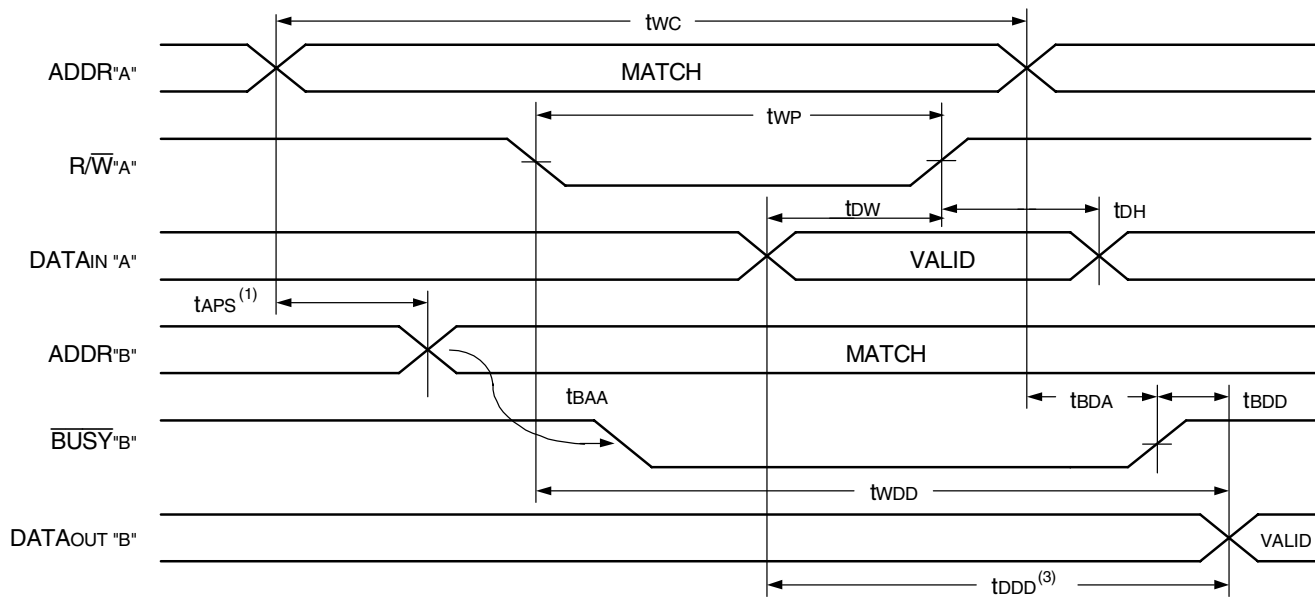
Symbol	Parameter	70V27X35 Com'l & Ind		70V27X55 Com'l Only		Unit
		Min.	Max.	Min.	Max.	
BUSY TIMING (M/ \overline{S} =V _{IH})						
t _{BAA}	$\overline{B}USY$ Access Time from Address Match	—	35	—	45	ns
t _{BDA}	$\overline{B}USY$ Disable Time from Address Not Matched	—	35	—	45	ns
t _{BAC}	$\overline{B}USY$ Access Time from Chip Enable Low	—	35	—	45	ns
t _{BDC}	$\overline{B}USY$ Disable Time from Chip Enable High	—	35	—	45	ns
t _{APS}	Arbitration Priority Set-up Time ⁽²⁾	5	—	5	—	ns
t _{BDD}	$\overline{B}USY$ Disable to Valid Data ⁽³⁾	—	40	—	50	ns
t _{WH}	Write Hold After $\overline{B}USY$ ⁽⁵⁾	25	—	25	—	ns
BUSY TIMING (M/ \overline{S} =V _{IL})						
t _{WB}	$\overline{B}USY$ Input to Write ⁽⁴⁾	0	—	0	—	ns
t _{WH}	Write Hold After $\overline{B}USY$ ⁽⁵⁾	25	—	25	—	ns
PORT-TO-PORT DELAY TIMING						
t _{WDD}	Write Pulse to Data Delay ⁽¹⁾	—	65	—	85	ns
t _{DDD}	Write Data Valid to Read Data Delay ⁽¹⁾	—	60	—	80	ns

3603 tbl 14b

NOTES:

- Port-to-port delay through RAM cells from writing port to reading port, refer to "Timing Waveform of Write with Port-to-Port Read and $\bar{B}USY$ (M/ \bar{S} = V_{IH})".
- To ensure that the earlier of the two ports wins.
- t_{BDD} is a calculated parameter and is the greater of 0, t_{WDD} – t_{WP} (actual), or t_{DDD} – t_{OW} (actual).
- To ensure that the write cycle is inhibited on port "B" during contention on port "A".
- To ensure that a write cycle is completed on port "B" after contention on port "A".
- 'X' in part numbers indicates power rating (S or L).

Timing Waveform of Write with Port-to-Port Read and $\overline{BUSY}^{(2,5)} (M/\overline{S} = V_{IH})^{(4)}$

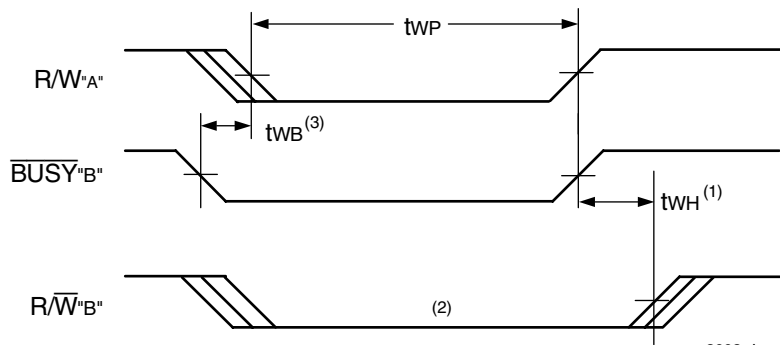


3603 drw 11

NOTES:

1. To ensure that the earlier of the two ports wins. t_{APS} is ignored for $M/\overline{S} = V_{IL}$ (SLAVE).
2. $\overline{CE_L} = \overline{CE_R} = V_{IL}$ (refer to Chip Enable Truth Table).
3. $\overline{OE} = V_{IL}$ for the reading port.
4. If $M/\overline{S} = V_{IL}$ (SLAVE), then \overline{BUSY} is an input. Then for this example \overline{BUSY} "A" = V_{IH} and \overline{BUSY} "B" = input is shown above.
5. All timing is the same for left and right ports. Port "A" may be either the left or right port. Port "B" is the port opposite from port "A".

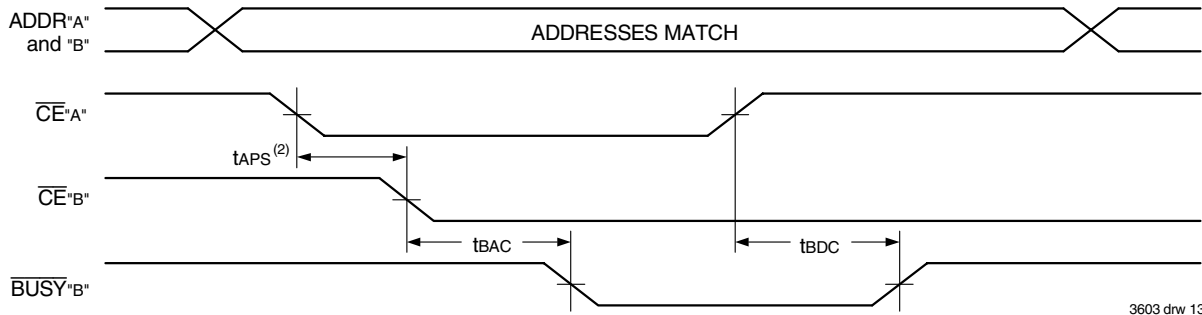
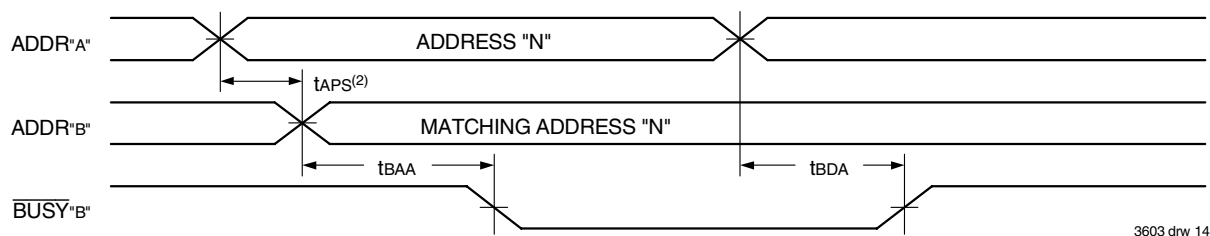
Timing Waveform Write with $\overline{BUSY} (M/\overline{S} = V_{IL})$



3603 drw 12

NOTES:

1. t_{WH} must be met for both \overline{BUSY} input (SLAVE) and output (MASTER).
2. \overline{BUSY} is asserted on port "B" blocking R/\overline{W} "B", until \overline{BUSY} "B" goes HIGH.
3. t_{WB} is only for the "Slave" version.

Waveform of $\overline{\text{BUSY}}$ Arbitration Controlled by $\overline{\text{CE}}$ Timing ($\text{M}/\overline{\text{S}} = \text{V}_{\text{IH}}$)^(1,3)**Waveform of $\overline{\text{BUSY}}$ Arbitration Cycle Controlled by Address Match Timing ($\text{M}/\overline{\text{S}} = \text{V}_{\text{IH}}$)⁽¹⁾****NOTES:**

1. All timing is the same for left and right ports. Port "A" may be either the left or right port. Port "B" is the port opposite from port "A".
2. If tAPS is not satisfied, the busy signal will be asserted on one side or another but there is no guarantee on which side busy will be asserted.
3. Refer to Chip Enable Truth Table.

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range⁽¹⁾

Symbol	Parameter	70V27X15 Com'l Only		70V27X20 Com'l & Ind		70V27X25 Com'l Only		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
INTERRUPT TIMING								
tAS	Address Set-up Time	0	—	0	—	0	—	ns
tWR	Write Recovery Time	0	—	0	—	0	—	ns
tINS	Interrupt Set Time	—	15	—	20	—	25	ns
tNR	Interrupt Reset Time	—	25	—	20	—	35	ns

3603 tbl 15a

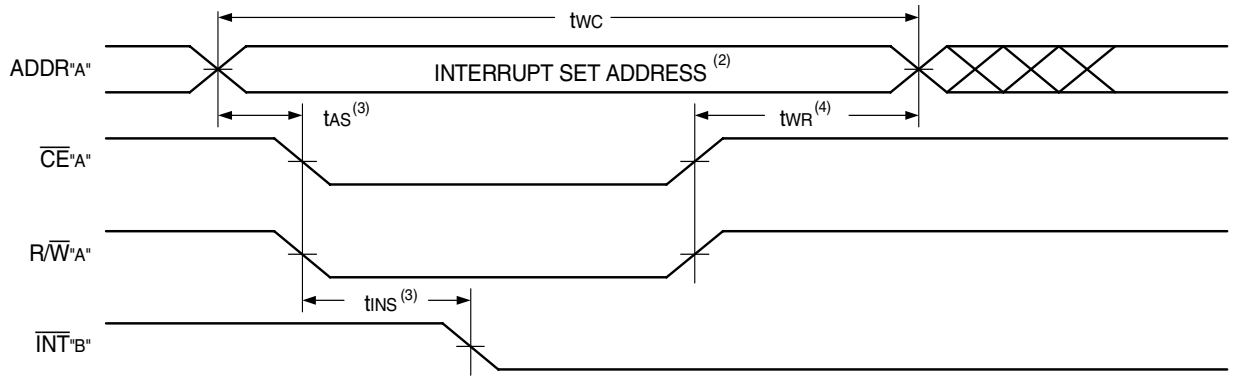
Symbol	Parameter	70V27X35 Com'l & Ind		70V27X55 Com'l Only		Unit
		Min.	Max.	Min.	Max.	
INTERRUPT TIMING						
tAS	Address Set-up Time	0	—	0	—	ns
tWR	Write Recovery Time	0	—	0	—	ns
tINS	Interrupt Set Time	—	30	—	40	ns
tNR	Interrupt Reset Time	—	35	—	45	ns

3603 tbl 15b

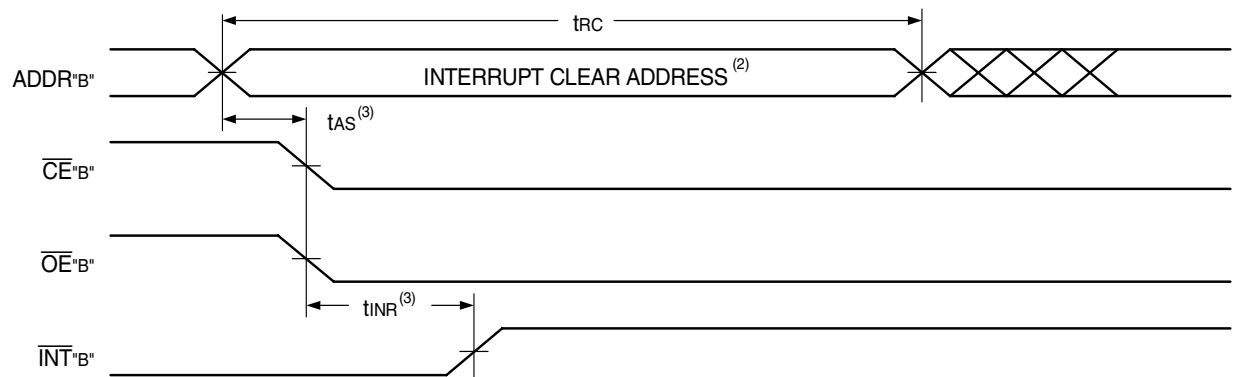
NOTES:

1. 'X' in part numbers indicates power rating (S or L).

Waveform of Interrupt Timing^(1,5)



3603 drw 15



3603 drw 16

NOTES:

1. All timing is the same for left and right ports. Port "A" may be either the left or right port. Port "B" is the port opposite from port "A".
2. See Interrupt Truth Table.
3. Timing depends on which enable signal (\overline{CE} or R/\overline{W}) is asserted last.
4. Timing depends on which enable signal (\overline{CE} or R/\overline{W}) is de-asserted first.
5. Refer to Chip Enable Truth Table.

Truth Table IV — Interrupt Flag^(1,4)

Left Port					Right Port					Function
R/\overline{W}_L	\overline{CE}_L	\overline{OE}_L	A14L-A0L	\overline{INT}_L	R/\overline{W}_R	\overline{CE}_R	\overline{OE}_R	A14R-A0R	\overline{INT}_R	
L	L	X	7FFF	X	X	X	X	X	L ⁽²⁾	Set Right \overline{INT}_R Flag
X	X	X	X	X	X	L	L	7FFF	H ⁽³⁾	Reset Right \overline{INT}_R Flag
X	X	X	X	L ⁽³⁾	L	L	X	7FFE	X	Set Left \overline{INT}_L Flag
X	L	L	7FFE	H ⁽²⁾	X	X	X	X	X	Reset Left \overline{INT}_L Flag

NOTES:

1. Assumes $\overline{BUSY}_L = \overline{BUSY}_R = V_{IH}$.
2. If $\overline{BUSY}_L = V_{IL}$, then no change.
3. If $\overline{BUSY}_R = V_{IL}$, then no change.
4. Refer to Chip Enable Truth Table.

3603 tbl 16

Truth Table V — Address $\overline{\text{BUSY}}$ Arbitration⁽⁴⁾

Inputs			Outputs		Function
$\overline{\text{CE}}_{\text{L}}$	$\overline{\text{CE}}_{\text{R}}$	A _{0L} -A _{14L} A _{0R} -A _{14R}	$\overline{\text{BUSY}}_{\text{L}}^{(1)}$	$\overline{\text{BUSY}}_{\text{R}}^{(1)}$	
X	X	NO MATCH	H	H	Normal
H	X	MATCH	H	H	Normal
X	H	MATCH	H	H	Normal
L	L	MATCH	(2)	(2)	Write Inhibit ⁽³⁾

3603 tbl 17

NOTES:

1. Pins $\overline{\text{BUSY}}_{\text{L}}$ and $\overline{\text{BUSY}}_{\text{R}}$ are both outputs when the part is configured as a master. Both are inputs when configured as a slave. $\overline{\text{BUSY}}$ outputs on the IDT70V27 are push-pull, not open drain outputs. On slaves the $\overline{\text{BUSY}}$ input internally inhibits writes.
2. "L" if the inputs to the opposite port were stable prior to the address and enable inputs of this port. "H" if the inputs to the opposite port became stable after the address and enable inputs of this port. If $\overline{\text{tAPS}}$ is not met, either $\overline{\text{BUSY}}_{\text{L}}$ or $\overline{\text{BUSY}}_{\text{R}}$ = LOW will result. $\overline{\text{BUSY}}_{\text{L}}$ and $\overline{\text{BUSY}}_{\text{R}}$ outputs can not be LOW simultaneously.
3. Writes to the left port are internally ignored when $\overline{\text{BUSY}}_{\text{L}}$ outputs are driving LOW regardless of actual logic level on the pin. Writes to the right port are internally ignored when $\overline{\text{BUSY}}_{\text{R}}$ outputs are driving LOW regardless of actual logic level on the pin.
4. Refer to Chip Enable Truth Table.

Truth Table VI — Example of Semaphore Procurement Sequence^(1,2)

Functions	D0 - D15 Left	D0 - D15 Right	Status
No Action	1	1	Semaphore free
Left Port Writes "0" to Semaphore	0	1	Left port has semaphore token
Right Port Writes "0" to Semaphore	0	1	No change. Right side has no write access to semaphore
Left Port Writes "1" to Semaphore	1	0	Right port obtains semaphore token
Left Port Writes "0" to Semaphore	1	0	No change. Left port has no write access to semaphore
Right Port Writes "1" to Semaphore	0	1	Left port obtains semaphore token
Left Port Writes "1" to Semaphore	1	1	Semaphore free
Right Port Writes "0" to Semaphore	1	0	Right port has semaphore token
Right Port Writes "1" to Semaphore	1	1	Semaphore free
Left Port Writes "0" to Semaphore	0	1	Left port has semaphore token
Left Port Writes "1" to Semaphore	1	1	Semaphore free

3603 tbl 18

NOTES:

1. This table denotes a sequence of events for only one of the eight semaphores on the IDT70V27.
2. There are eight semaphore flags written to via I/O₀ and read from all the I/O's (I/O₀-I/O₁₅). These eight semaphores are addressed by A₀ - A₂.

Functional Description

The IDT70V27 provides two ports with separate control, address and I/O pins that permit independent access for reads or writes to any location in memory. The IDT70V27 has an automatic power down feature controlled by $\overline{\text{CE}}_0$ and CE_1 . The $\overline{\text{CE}}_0$ and CE_1 control the on-chip power down circuitry that permits the respective port to go into a standby mode when not selected ($\overline{\text{CE}}$ HIGH). When a port is enabled, access to the entire memory array is permitted.

Interrupts

If the user chooses the interrupt function, a memory location (mail box or message center) is assigned to each port. The left port interrupt flag ($\overline{\text{INT}}_{\text{L}}$) is asserted when the right port writes to memory location 7FFE (HEX), where a write is defined as $\overline{\text{CE}}_{\text{R}} = \text{R}/\overline{\text{W}}_{\text{R}} = \text{V}_{\text{IL}}$ per the Truth Table IV. The left port clears the interrupt through access of address location

7FFE when $\overline{\text{CE}}_{\text{L}} = \overline{\text{OE}}_{\text{L}} = \text{V}_{\text{IL}}$, $\text{R}/\overline{\text{W}}$ is a "don't care". Likewise, the right port interrupt flag ($\overline{\text{INT}}_{\text{R}}$) is asserted when the left port writes to memory location 7FFF (HEX) and to clear the interrupt flag ($\overline{\text{INT}}_{\text{R}}$), the right port must read the memory location 7FFF. The message (16 bits) at 7FFE or 7FFF is user-defined since it is an addressable SRAM location. If the interrupt function is not used, address locations 7FFE and 7FFF are not used as mail boxes, but as part of the random access memory. Refer to Truth Table IV for the interrupt operation.

Busy Logic

Busy Logic provides a hardware indication that both ports of the RAM have accessed the same location at the same time. It also allows one of the two accesses to proceed and signals the other side that the RAM is "Busy". The $\overline{\text{BUSY}}$ pin can then be used to stall the access until the operation on

the other side is completed. If a write operation has been attempted from the side that receives a $\overline{\text{BUSY}}$ indication, the write signal is gated internally to prevent the write from proceeding.

The use of $\overline{\text{BUSY}}$ logic is not required or desirable for all applications. In some cases it may be useful to logically OR the $\overline{\text{BUSY}}$ outputs together and use any $\overline{\text{BUSY}}$ indication as an interrupt source to flag the event of an illegal or illogical operation. If the write inhibit function of $\overline{\text{BUSY}}$ logic is not desirable, the $\overline{\text{BUSY}}$ logic can be disabled by placing the part in slave mode with the $\overline{\text{M/S}}$ pin. Once in slave mode the $\overline{\text{BUSY}}$ pin operates solely as a write inhibit input pin. Normal operation can be programmed by tying the $\overline{\text{BUSY}}$ pins HIGH. If desired, unintended write operations can be prevented to a port by tying the $\overline{\text{BUSY}}$ pin for that port LOW.

The $\overline{\text{BUSY}}$ outputs on the IDT 70V27 RAM in master mode, are push-pull type outputs and do not require pull up resistors to operate. If these RAMs are being expanded in depth, then the $\overline{\text{BUSY}}$ indication for the resulting array requires the use of an external AND gate.

Width Expansion with $\overline{\text{BUSY}}$ Logic Master/Slave Arrays

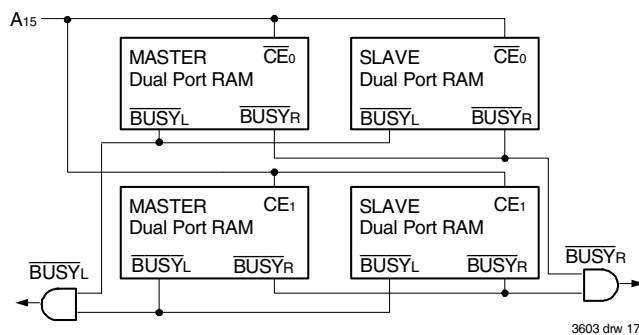


Figure 3. Busy and chip enable routing for both width and depth expansion with IDT70V27 RAMs.

When expanding an IDT70V27 RAM array in width while using $\overline{\text{BUSY}}$ logic, one master part is used to decide which side of the RAM array will receive a $\overline{\text{BUSY}}$ indication, and to output that indication. Any number of slaves to be addressed in the same address range as the master, use the busy signal as a write inhibit signal. Thus on the IDT70V27 RAM the $\overline{\text{BUSY}}$ pin is an output if the part is used as a master ($\overline{\text{M/S}}$ pin = V_{IH}), and the $\overline{\text{BUSY}}$ pin is an input if the part is used as a slave ($\overline{\text{M/S}}$ pin = V_{IL}) as shown in Figure 3.

If two or more master parts were used when expanding in width, a split decision could result with one master indicating $\overline{\text{BUSY}}$ on one side of the array and another master indicating $\overline{\text{BUSY}}$ on one other side of the array. This would inhibit the write operations from one port for part of a word and inhibit the write operations from the other port for the other part of the word.

The $\overline{\text{BUSY}}$ arbitration, on a master, is based on the chip enable and address signals only. It ignores whether an access is a read or write. In a master/slave array, both address and chip enable must be valid long enough for a $\overline{\text{BUSY}}$ flag to be output from the master before the actual write pulse can be initiated with either the $\overline{\text{R/W}}$ signal or the byte enables. Failure to observe this timing can result in a glitched internal write inhibit signal and corrupted data in the slave.

Semaphores

The IDT70V27 is a fast Dual-Port 32K x 16 CMOS Static RAM with an additional 8 address locations dedicated to binary semaphore flags. These flags allow either processor on the left or right side of the Dual-Port RAM to claim a privilege over the other processor for functions defined by the system designer's software. As an example, the semaphore can be used by one processor to inhibit the other from accessing a portion of the Dual-Port RAM or any other shared resource.

The Dual-Port RAM features a fast access time, and both ports are completely independent of each other. This means that the activity on the left port in no way slows the access time of the right port. Both ports are identical in function to standard CMOS Static RAM and can be read from, or written to, at the same time with the only possible conflict arising from the simultaneous writing of, or a simultaneous READ/WRITE of, a non-semaphore location. Semaphores are protected against such ambiguous situations and may be used by the system program to avoid any conflicts in the non-semaphore portion of the Dual-Port RAM. These devices have an automatic power-down feature controlled by $\overline{\text{CE}}$ the Dual-Port RAM enable, and $\overline{\text{SEM}}$, the semaphore enable. The $\overline{\text{CE}}$ and $\overline{\text{SEM}}$ pins control on-chip power down circuitry that permits the respective port to go into standby mode when not selected. This is the condition which is shown in Truth Table II where $\overline{\text{CE}}$ and $\overline{\text{SEM}}$ are both HIGH.

Systems which can best use the IDT70V27 contain multiple processors or controllers and are typically very high-speed systems which are software controlled or software intensive. These systems can benefit from a performance increase offered by the IDT70V27's hardware semaphores, which provide a lockout mechanism without requiring complex programming.

Software handshaking between processors offers the maximum in system flexibility by permitting shared resources to be allocated in varying configurations. The IDT70V27 does not use its semaphore flags to control any resources through hardware, thus allowing the system designer total flexibility in system architecture.

An advantage of using semaphores rather than the more common methods of hardware arbitration is that wait states are never incurred in either processor. This can prove to be a major advantage in very high-speed systems.

How the Semaphore Flags Work

The semaphore logic is a set of eight latches which are independent of the Dual-Port RAM. These latches can be used to pass a flag, or token, from one port to the other to indicate that a shared resource is in use. The semaphores provide a hardware assist for a use assignment method called "Token Passing Allocation." In this method, the state of a semaphore latch is used as a token indicating that shared resource is in use. If the left processor wants to use this resource, it requests the token by setting the latch. This processor then verifies its success in setting the latch by reading it. If it was successful, it proceeds to assume control over the shared resource. If it was not successful in setting the latch, it determines that the right side processor has set the latch first, has the token and is using the shared resource. The left processor can then either repeatedly request that semaphore's status or remove its request for that semaphore to perform another task and occasionally attempt again to gain control of the token via the set and test sequence. Once the right side has relinquished the token, the left side should succeed in gaining control.

The semaphore flags are active low. A token is requested by writing a zero into a semaphore latch and is released when the same side writes a one to that latch.

The eight semaphore flags reside within the IDT70V27 in a separate memory space from the Dual-Port RAM. This address space is accessed by placing a low input on the $\overline{\text{SEM}}$ pin (which acts as a chip select for the semaphore flags) and using the other control pins (Address, $\overline{\text{OE}}$, and $\text{R}/\overline{\text{W}}$) as they would be used in accessing a standard Static RAM. Each of the flags has a unique address which can be accessed by either side through address pins A0–A2. When accessing the semaphores, none of the other address pins has any effect.

When writing to a semaphore, only data pin D0 is used. If a low level is written into an unused semaphore location, that flag will be set to a zero on that side and a one on the other side (see Table VI). That semaphore can now only be modified by the side showing the zero. When a one is written into the same location from the same side, the flag will be set to a one for both sides (unless a semaphore request from the other side is pending) and then can be written to by both sides. The fact that the side which is able to write a zero into a semaphore subsequently locks out writes from the other side is what makes semaphore flags useful in interprocessor communications. (A thorough discussion on the use of this feature follows shortly.) A zero written into the same location from the other side will be stored in the semaphore request latch for that side until the semaphore is freed by the first side.

When a semaphore flag is read, its value is spread into all data bits so that a flag that is a one reads as a one in all data bits and a flag containing a zero reads as all zeros. The read value is latched into one side's output register when that side's semaphore select ($\overline{\text{SEM}}$) and output enable ($\overline{\text{OE}}$) signals go active. This serves to disallow the semaphore from changing state in the middle of a read cycle due to a write cycle from the other side. Because of this latch, a repeated read of a semaphore in a test loop must cause either signal ($\overline{\text{SEM}}$ or $\overline{\text{OE}}$) to go inactive or the output will never change.

A sequence WRITE/READ must be used by the semaphore in order to guarantee that no system level contention will occur. A processor requests access to shared resources by attempting to write a zero into a semaphore location. If the semaphore is already in use, the semaphore request latch will contain a zero, yet the semaphore flag will appear as a one, a fact which the processor will verify by the subsequent read (see Table VI). As an example, assume a processor writes a zero to the left port at a free semaphore location. On a subsequent read, the processor will verify that it has written successfully to that location and will assume control over the resource in question. Meanwhile, if a processor on the right side attempts to write a zero to the same semaphore flag it will fail, as will be verified by the fact that a one will be read from that semaphore on the right side during the subsequent read. Had a sequence of READ/WRITE been

used instead, system contention problems could have occurred during the gap between the read and write cycles.

It is important to note that a failed semaphore request must be followed by either repeated reads or by writing a one into the same location. The

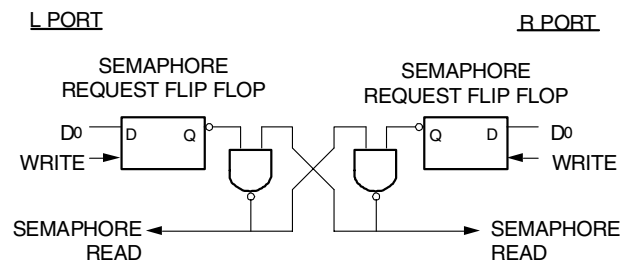


Figure 4. IDT70V27 Semaphore Logic 3603 drw 18

reason for this is easily understood by looking at the simple logic diagram of the semaphore flag in Figure 4. Two semaphore request latches feed into a semaphore flag. Whichever latch is first to present a zero to the semaphore flag will force its side of the semaphore flag low and the other side high. This condition will continue until a one is written to the same semaphore request latch. Should the other side's semaphore request latch have been written to a zero in the meantime, the semaphore flag will flip over to the other side as soon as a one is written into the first side's request latch. The second side's flag will now stay low until its semaphore request latch is written to a one. From this it is easy to understand that, if a semaphore is requested and the processor which requested it no longer needs the resource, the entire system can hang up until a one is written into that semaphore request latch.

The critical case of semaphore timing is when both sides request a single token by attempting to write a zero into it at the same time. The semaphore logic is specially designed to resolve this problem. If simultaneous requests are made, the logic guarantees that only one side receives the token. If one side is earlier than the other in making the request, the first side to make the request will receive the token. If both requests arrive at the same time, the assignment will be arbitrarily made to one port or the other.

One caution that should be noted when using semaphores is that semaphores alone do not guarantee that access to a resource is secure. As with any powerful programming technique, if semaphores are misused or misinterpreted, a software error can easily happen.

Initialization of the semaphores is not automatic and must be handled via the initialization program at power-up. Since any semaphore request flag which contains a zero must be reset to a one, all semaphores on both sides should have a one written into them at initialization from both sides to assure that they will be free when needed.

Ordering Information

XXXXX	A	999	A	A	A	A		
Device Type	Power	Speed	Package		Process/ Temperature Range			
							Blank 8	Tube or Tray Tape and Reel
							Blank I ⁽¹⁾	Commercial (0°C to +70°C) Industrial (-40°C to +85°C)
							G ⁽²⁾	Green
							BF PF	144-pin fpBGA (BF144-1) 100-pin TQFP (PN100-1)
							15 20 25 35 55	Commercial Only Commercial & Industrial Commercial Only Commercial & Industrial Commercial Only
							S L	Standard Power Low Power
							70V27	512K (32K x 16) 3.3V Dual-Port RAM

3603drw19

NOTES:

- Industrial temperature range is available on selected TQFP packages in low power.
For other speeds, packages and powers contact your sales office.
- Green parts available. For specific speeds, packages and powers contact your local sales office.

Datasheet Document History

12/03/98:		Initiated Document History Converted to new format Typographical and cosmetic changes Added fpBGA information Added 15ns and 20ns speed grades Updated DC Electrical Characteristics Added additional notes to pin configurations
04/02/99:	Page 5	Fixed typo in Table III
08/01/99:	Page 3	Changed package body height from 1.1mm to 1.4mm
08/30/99:	Page 1	Changed 660mW to 660μW
04/25/00:		Replaced IDT logo
	Page 2	Made pin correction Changed ±200mV to 0mV in notes

Datasheet Document History continued on page 21

Datasheet Document History(cont'd)

01/12/01:	Page 1	Fixed page numbering; copyright
	Page 6	Increased storage temperature parameter Clarified TA Parameter
	Page 7 & 8	DC Electrical parameters--changed wording from "open" to "disabled" Removed Preliminary status
08/02/04:	Page 1, 4 & 20	Removed GU-108 package offering
	Page 2 & 3	Added date revision for pin configurations
	Page 2 - 7	Changed naming convention from V _{CC} to V _{DD} and from GND to V _{SS}
	Page 5	Updated Capacitance table
	Page 6	Added I-temp for low power for 20ns speed to DC Electrical Characteristics
	Page 6 - 7	Removed I-temp for 25ns & 55ns speeds and removed I-temp for 35ns standard power from DC Electrical Characteristics
	Page 7	Changed Input Rise/Fall Times from 5ns to 3ns
	Page 8, 10, 13 & 15	Removed I-temp for 25ns & 55ns speeds from AC Electrical Characteristics for Read, Write, Busy and Interrupt
01/20/06:	Page 6 - 8, 10, 13 & 15	Removed I-temp note from all table footnotes
	Page 1	Added green availability to features
09/21/06:	Page 20	Added green indicator to ordering information
	Page 20	Added die stepping indicator to ordering information
10/23/08:	Page 20	Removed "IDT" from orderable part number
09/27/12:	Page 20	Added T&R indicator to and removed W stepping from ordering information
	Page 2, 17 & 19	Corrected miscellaneous typo's



CORPORATE HEADQUARTERS
6024 Silver Creek Valley Road
San Jose, CA 95138

for SALES:
800-345-7015 or 408-284-8200
fax: 408-284-2775
www.idt.com

for Tech Support:
408-284-2794
DualPortHelp@idt.com

The IDT logo is a registered trademark of Integrated Device Technology, Inc.